

United States Patent and Trademark Office

STATES DEPARTMENT OF COMMERCE

UNITED STATES DEPARTMENT OF COMMERCE
United States Patent and Trademark Office
Address: COMMISSIONER FOR PATENTS
P.O. Box 1450
Alexandria, Virginia 22313-1450
www.uspto.gov

APPLICATION NO.	F	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/627,069		07/25/2003	Martin E. Fermann	IMRAA.021A	2229	
20995	7590	08/08/2005		EXAM	EXAMINER	
	NOBBE MARTENS OLSON & BEAR LLP			FLORES RUIZ, DELMA R		
2040 MAIN FOURTEE				ART UNIT	PAPER NUMBER	
IRVINE, C	A 92614	•		2828		
				DATE MAILED: 08/08/2009	5	

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application No.	Applicant(s)		
		10/627,069	FERMANN ET AL.		
Office A	ction Summary	Examiner	Art Unit		
		Delma R. Flores Ruiz	2828		
The MAILING Period for Reply	ODATE of this communication app	ears on the cover sheet with the c	orrespondence address		
THE MAILING DAT - Extensions of time may be after SIX (6) MONTHS from the period for reply specified by the same and the period for reply is second to reply within the Any reply received by the	ATUTORY PERIOD FOR REPLY E OF THIS COMMUNICATION. The available under the provisions of 37 CFR 1.13 om the mailing date of this communication. Cified above is less than thirty (30) days, a reply pecified above, the maximum statutory period waset or extended period for reply will, by statute, office later than three months after the mailing transt. See 37 CFR 1.704(b).	86(a). In no event, however, may a reply be time within the statutory minimum of thirty (30) day rill apply and will expire SIX (6) MONTHS from cause the application to become ABANDONE	nely filed s will be considered timely. the mailing date of this communication. D (35 U.S.C. § 133).		
Status					
1) Responsive to	o communication(s) filed on <u>09 Ju</u>	ne 2005.			
2a) This action is	FINAL. 2b)⊠ This	action is non-final.			
, , , , , , , , , , , , , , , , , , , ,	olication is in condition for allowar ordance with the practice under <i>E</i>				
Disposition of Claims					
4a) Of the abo 5) ☐ Claim(s) 6) ☒ Claim(s) <u>35-4</u> 7) ☒ Claim(s) <u>42-4</u>	1,45-49 and 65 is/are rejected.	32 and 50 - 64 is/are withdrawn	from consideration.		
Application Papers					
9) ☐ The specificati	on is objected to by the Examiner	r.			
10) The drawing (s) filed on <u>25 <i>July 2003</i> is/are:</u> a)[\square accepted or b) $igtimes$ objected to b	y the Examiner.		
Applicant may i	not request that any objection to the o	drawing(s) be held in abeyance. See	e 37 CFR 1.85(a).		
<u> </u>	rawing sheet(s) including the correctic claration is objected to by the Ex-		• •		
Priority under 35 U.S.0	C. § 119				
 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 					
Attachment(s)		_			
 Notice of References C Notice of Draftsperson' 	cited (PTO-892) s Patent Drawing Review (PTO-948)	4)			
	Statement(s) (PTO-1449 or PTO/SB/08)		atent Application (PTO-152)		

Application/Control Number: 10/627,069 Page 2

Art Unit: 2828

DETAILED ACTION

Election/Restrictions

Applicant's election with traverse of Group I, a claim 35 – 49 and 65 in the reply filed on 06/09/2005 is acknowledged. The traversal is on the ground(s) that the applicant don't argument why is the election is with traverse. This is not found persuasive because the combination as claimed does not require the particulars of the subcombination as claimed for patentability, and that the subcombination has utility by itself or in other combinations (MPEP § 806.05(c)).

The requirement is still deemed proper and is therefore made FINAL.

Claims 2, 6 –9, 14 – 27, 31 – 32 and 50 - 64 are withdrawn from further consideration pursuant to 37 CFR 1.142(b), as being drawn to a nonelected restriction, there being no allowable generic or linking claim. Applicant timely traversed the restriction (election) requirement in the reply filed on 06/09/2005.

Information Disclosure Statement

The information disclosure statement (IDS) submitted on 04/15/2005 and 10/27/2003 have been considered by the examiner.

Drawings

The drawings are objected to under 37 CFR 1.83(a). The drawings must show every feature of the invention specified in the claims. Therefore, the film of a semiconductor material implanted with high-energy ions at a penetration depth, which differs from the penetration depth of optical signals reflected from said saturable absorber mirror, must be shown or the feature(s) canceled from the claim(s). No new matter should be entered.

Corrected drawing sheets in compliance with 37 CFR 1.121(d) are required in reply to the Office action to avoid abandonment of the application. Any amended replacement drawing sheet should include all of the figures appearing on the immediate prior version of the sheet, even if only one figure is being amended. The figure or figure number of an amended drawing should not be labeled as "amended." If a drawing figure is to be canceled, the appropriate figure must be removed from the replacement sheet, and where necessary, the remaining figures must be renumbered and appropriate changes made to the brief description of the several views of the drawings for consistency. Additional replacement sheets may be necessary to show the renumbering of the remaining figures. Each drawing sheet submitted after the filing date of an application must be labeled in the top margin as either "Replacement Sheet" or "New Sheet" pursuant to 37 CFR 1.121(d). If the changes are not accepted by the examiner,

Art Unit: 2828

the applicant will be notified and informed of any required corrective action in the next Office action. The objection to the drawings will not be held in abeyance.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claims 35, 36, 45 – 48 are rejected under 35 U.S.C. 102(e) as being anticipated by Kaneko (US 2002/0105711 A1).

Regarding claim 35, Kaneko discloses a saturable absorber mirror for passive modelocking of lasers, comprising: a film (see Fig. 2 Character 154) of a semiconductor material implanted with high energy ions at a penetration depth which differs from the penetration depth of optical signals reflected from said saturable absorber mirror (Fig. 2, Paragraphs 11 and 13).

Regarding claim 36, Kaneko discloses the thickness of said film is selected to be in the range of 50 nm-2000 nm (Paragraph 70, 1μ m = 1000nm).

Regarding claims 45 – 47, Kaneko discloses a semiconductor film comprises a combination of a bulk semiconductor and a multiple quantum well structure (Paragraphs 53, 55 and 65).

Regarding claim 48, Kaneko disclose a film of a semiconductor material implanted with high-energy ions at a penetration depth which is smaller than the penetration depth of optical signals reflected from said saturable absorber mirror (Fig. 2, Paragraphs 2 and 13).

Claim 65 is rejected under 35 U.S.C. 102(e) as being anticipated by Hong et la (2003/0147134).

Regarding claim 65, Hong discloses a InGaAsP fabricated with a bandgap in the 1.0-1.1 um wavelength region (Paragraph 56).

Application/Control Number: 10/627,069

Art Unit: 2828

Discloses Figure 2 by Kaneko (US 2002/0105711)

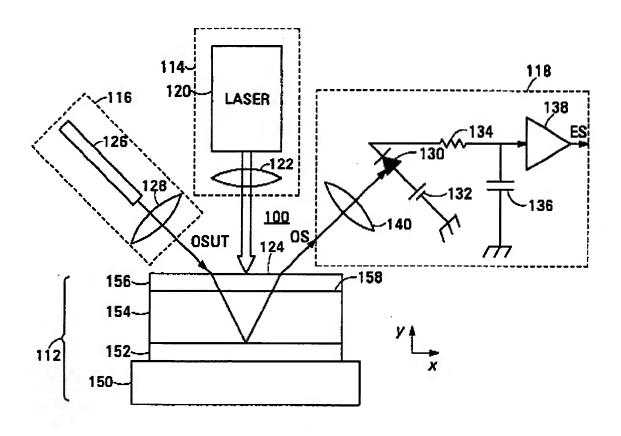


FIG.2

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claim 49 is rejected under 35 U.S.C. 102(b) as being anticipated by Yamazaki et al (2001/0034089).

Regarding claim 49, Yamazaki discloses a saturable absorber to be operated in transmission for passive modelocking of lasers, comprising: a film of a semiconductor material implanted with high energy ions at a penetration depth which is smaller than the thickness of said film (Paragraph 29).

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 37 – 40 are rejected under 35 U.S.C. 103(a) as being unpatentable over Kaneko (US 2002/0105711 A1) in view of Ooi et al (US 2002/0072142 A1)

Regarding claims 37 – 40, Kaneko discloses the claimed invention except for

Page 8

high energy ions comprise protons, arsenic or beryllium; implantation dosage of said high energy ions is in a range 10.sup.12-10.sup.17 ions/cm², high energy ions comprise arsenic, and wherein the implantation energy is in the range of 100 keV-1000 keV. Ooi discloses a high energy ions comprise protons, arsenic or beryllium; implantation dosage of said high energy ions is in a range 10.sup.12-10.sup.17 ions/cm², high energy ions comprise arsenic, and wherein the implantation energy is in the range of 100 keV-1000 keV. It would have been obvious at the time of applicant's invention, to combine Ooi of teaching a energy ions comprise protons, arsenic or beryllium; implantation dosage of said high energy ions is in a range 10.sup.12-10.sup.17 ions/cm², high energy ions comprise arsenic, and wherein the implantation energy is in the range of 100 keV-1000 keV (Paragraphs 66, 84 and 85) with saturable absorber because generated relatively shallow point defects in the implanted material and, thus, produced no direct damage to the QW layers.

Claim 41 is rejected under 35 U.S.C. 103(a) as being unpatentable over Kaneko (US 2002/0105711 A1) in view of Goedertier (3,500,234).

Regarding claim 41, Kaneko discloses the claimed invention except for one surface of mirror is anti-reflection-coated. Goedertier discloses surface of mirror is antireflection-coated. It would have been obvious at the time of applicant's invention, to .

Application/Control Number: 10/627,069

Art Unit: 2828

combine Goedertier of teaching a said mirror is anti-reflection-coated with saturable absorber because anti-reflection coating use to decrease reflection losses at the interface of said one end and said saturable absorber (claim 3).

Allowable Subject Matter

Claims 42 – 44 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Delma R. Flores Ruiz whose telephone number is (571) 272-1940. The examiner can normally be reached on M - F.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Min Sun Harvey can be reached on (571) -272-1835. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306. Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR.

Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Delma R. Flores Ruiz

Examiner
Art Unit 2828

DRFR/MH July 26, 2005 MENERFEE

Min Sun Harvey
Supervisor Patent Examiner
Art Unit 2828